



## 54FCT/74FCT241A

# Octal Buffer/Line Driver with TRI-STATE® Outputs

### General Description

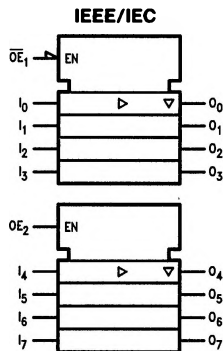
The 'FCT241A is an octal buffer and line driver designed to be employed as a memory address driver, clock driver and bus-oriented transmitter or receiver which provides improved PC board density.

### Features

- NSC 54/74FCT241A is pin and functionally equivalent to IDT 54/74FCT241A
- Non-inverting TRI-STATE outputs drive bus lines or buffer memory address registers
- 'FCT241A has TTL-compatible inputs
- Military product compliant to MIL-STD-883C
- Inherently radiation tolerant
- $I_{OL} = 64 \text{ mA (Comm)}$  and  $48 \text{ mA (Mil)}$
- TTL input and output level compatible
- High current latch up

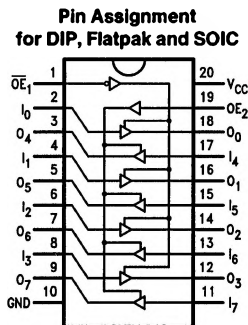
**Ordering Code:** See Section 8

### Logic Symbol

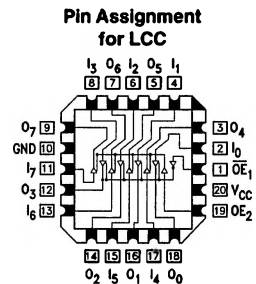


TL/F/10269-1

### Connection Diagrams



TL/F/10269-2



TL/F/10269-3

Pin Names	Description
$\overline{OE}_1$	TRI-STATE Output Enable Input
$\overline{OE}_2$	TRI-STATE Output Enable Input (Active HIGH)
$I_0$ - $I_7$	Inputs
$O_0$ - $O_7$	Outputs

### Truth Tables

Inputs		Outputs (Pins 12, 14, 16, 18)
$\overline{OE}_1$	D	
L	L	L
L	H	H
H	X	Z

Inputs		Outputs (Pins 3, 5, 7, 9)
$\overline{OE}_2$	D	
H	L	L
H	H	H
L	X	Z

H = HIGH Voltage Level  
 L = LOW Voltage Level  
 X = Immaterial  
 Z = High Impedance

**Absolute Maximum Ratings** (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Terminal Voltage with Respect to GND ( $V_{TERM}$ )	
74FCTA	-0.5V to 7.0V
54FCTA	-0.5V to 7.0V
Temperature under Bias ( $T_{BIAS}$ )	
74FCTA	-55°C to +125°C
54FCTA	-65°C to +135°C
Storage Temperature ( $T_{STG}$ )	
74FCTA	-55°C to +125°C
54FCTA	-65°C to +150°C
Power Dissipation ( $P_T$ )	0.5W
DC Output Current ( $I_{OUT}$ )	120 mA

**Note 1:** Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. National does not recommend operation of FACT™ FCT circuits outside databook specifications.

**Recommended Operating Conditions**

Supply Voltage ( $V_{CC}$ )	
54FCTA	4.5V to 5.5V
74FCTA	4.75V to 5.25V
Input Voltage	0V to $V_{CC}$
Output Voltage	0V to $V_{CC}$
Operating Temperature ( $T_A$ )	
54FCTA	-55°C to +125°C
74FCTA	-0°C to +70°C
Junction Temperature ( $T_J$ )	
CDIP	175°C
PDIP	140°C

**DC Characteristics for 'FCTA Family Devices**

Typical values are at  $V_{CC} = 5.0V$ , 25°C ambient and maximum loading. For test conditions shown as Max, use the value specified for the appropriate device type: Com:  $V_{CC} = 5.0V \pm 5\%$ ,  $T_A = 0^\circ C$  to  $+70^\circ C$ ; Mil:  $V_{CC} = 5.0V \pm 10\%$ ,  $T_A = -55^\circ C$  to  $+125^\circ C$ ,  $V_{HC} = V_{CC} - 0.2V$

Symbol	Parameter	54FCTA/74FCTA			Units	Conditions	
		Min	Typ	Max			
$V_{IH}$	Minimum High Level Input Voltage	2.0			V		
$V_{IL}$	Maximum Low Level Input Voltage	0.8			V		
$I_{IH}$	Input High Current	5.0 5.0			$\mu A$	$V_{CC} = \text{Max}$	$V_I = V_{CC}$ $V_I = 2.7V$ (Note 2)
$I_{IL}$	Input Low Current	-5.0 -5.0			$\mu A$	$V_{CC} = \text{Max}$	$V_I = 0.5V$ (Note 2) $V_I = GND$
$I_{OZ}$	Maximum TRI-STATE Current	10.0 10.0 -10.0 -10.0			$\mu A$	$V_{CC} = \text{Max}$	$V_O = V_{CC}$ $V_O = 2.7V$ (Note 2) $V_O = 0.5V$ (Note 2) $V_O = GND$
$V_{IK}$	Clamp Diode Voltage	-0.7 -1.2			V	$V_{CC} = \text{Min}; I_N = -18 \text{ mA}$	
$I_{OS}$	Short Circuit Current	-60 -120			mA	$V_{CC} = \text{Max}$ (Note 1); $V_O = GND$	
$V_{OH}$	Minimum High Level Output Voltage	2.8 3.0		V	$V_{CC} = 3V; V_{IN} = 0.2V$ or $V_{HC}; I_{OH} = -32 \mu A$		
		$V_{HC}$	$V_{CC}$		$V_{CC} = \text{Min}$		$I_{OH} = -300 \mu A$
		2.4 4.3 2.4 4.3	$V_{IN} = V_{IH}$ or $V_{IL}$		$I_{OH} = -12 \text{ mA}$ (Mil) $I_{OH} = -15 \text{ mA}$ (Com)		
$V_{OL}$	Maximum Low Level Output Voltage	GND 0.2		V	$V_{CC} = 3V; V_{IN} = 0.2V$ or $V_{HC}; I_{OL} = 300 \mu A$		
		GND 0.2			$V_{CC} = \text{Min}$		$I_{OL} = 300 \mu A$
		0.3 0.55			$V_{IN} = V_{IH}$ or $V_{IL}$		$I_{OL} = 48 \text{ mA}$ (Mil)
		0.3 0.55					$I_{OL} = 64 \text{ mA}$ (Com)
$I_{CC}$	Maximum Quiescent Supply Current	0.001 1.5			mA	$V_{CC} = \text{Max}$ $V_{IN} \geq V_{HC}; V_{IN} \leq 0.2V$ $f_I = 0$	
$\Delta I_{CC}$	Quiescent Supply Current; TTL Inputs HIGH	0.5 2.0			mA	$V_{CC} = \text{Max}$ $V_{IN} = 3.4V$ (Note 3)	

## DC Characteristics for 'FCTA Family Devices (Continued)

Typical values are at  $V_{CC} = 5.0V$ , 25°C ambient and maximum loading. For test conditions shown as Max, use the value specified for the appropriate device type: Com:  $V_{CC} = 5.0V \pm 5\%$ ,  $T_A = 0^\circ C$  to  $+70^\circ C$ ; Mil:  $V_{CC} = 5.0V \pm 10\%$ ,  $T_A = -55^\circ C$  to  $+125^\circ C$ ,  $V_{HC} = V_{CC} - 0.2V$

Symbol	Parameter	54FCTA/74FCTA			Units	Conditions	
		Min	Typ	Max			
$I_{CCD}$	Dynamic Power Supply Current (Note 4)		0.25	0.40	mA/MHz	$V_{CC} = \text{Max}$ Outputs Open $\overline{OE}_A = \overline{OE}_B = \text{GND}$ One Input Toggling 50% Duty Cycle	$V_{IN} \geq V_{HC}$ $V_{IN} \leq 0.2V$
$I_C$	Total Power Supply Current (Note 6)		1.5	4.5	mA	$V_{CC} = \text{Max}$ Outputs Open $\overline{OE}_A = \overline{OE}_B = \text{GND}$  $f_1 = 10 \text{ MHz}$ One Bit Toggling 50% Duty Cycle	$V_{IN} \geq V_{HC}$ $V_{IN} \leq 0.2V$
			1.8	5.0		$V_{IN} = 3.4V$ $V_{IN} = \text{GND}$	
			3.0	8.0		(Note 5) $V_{CC} = \text{Max}$ Outputs Open $\overline{OE}_A = \overline{OE}_B = \text{GND}$	$V_{IN} \geq V_{HC}$ $V_{IN} \leq 0.2V$
			5.0	14.5		$f_1 = 2.5 \text{ MHz}$ Eight Bits Toggling 50% Duty Cycle	$V_{IN} = 3.4V$ $V_{IN} = \text{GND}$
$V_H$	Input Hysteresis on Clock Only		200		mV		

**Note 1:** Maximum test duration not to exceed one second, not more than one output shorted at one time.

**Note 2:** This parameter guaranteed but not tested.

**Note 3:** Per TTL driven input ( $V_{IN} = 3.4V$ ); all other inputs at  $V_{CC}$  or GND.

**Note 4:** This parameter is not directly testable, but is derived for use in Total Power Supply calculations.

**Note 5:** Values for these conditions are examples of the  $I_{CC}$  formula. These limits are guaranteed but not tested.

**Note 6:**  $I_C = I_{QUIESCENT} + I_{INPUTS} + I_{DYNAMIC}$   
 $I_C = I_{CC} + \Delta I_{CC} D_H N_T + I_{CCD} (f_{CP}/2 + f_1 N_i)$   
 $I_{CC}$  = Quiescent Current  
 $\Delta I_{CC}$  = Power Supply Current for a TTL High Input ( $V_{IN} = 3.4V$ )  
 $D_H$  = Duty Cycle for TTL Inputs High  
 $N_T$  = Number of Inputs at  $D_H$   
 $I_{CCD}$  = Dynamic Current Caused by an Input Transition Pair (HLH or LHL)  
 $f_{CP}$  = Clock Frequency for Register Devices (Zero for Non-Register Devices)  
 $f_1$  = Input Frequency  
 $N_i$  = Number of Inputs at  $f_1$   
 All currents are in milliamps and all frequencies are in megahertz.

**AC Electrical Characteristics:** See Section 2 for Waveforms

Symbol	Parameter	54FCTA/74FCTA	74FCTA		54FCTA		Units	Fig. No.
		$T_A = +25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$	$T_A, V_{CC} = \text{Com}$ $R_L = 500\Omega$ $C_L = 50\text{pF}$		$T_A, V_{CC} = \text{MII}$ $R_L = 500\Omega$ $C_L = 50\text{pF}$			
		Typ	Min (Note 1)	Max	Min (Note 1)	Max		
$t_{PLH}$ $t_{PHL}$	Propagation Delay $D_n$ to $O_n$	3.0	1.5	4.8			ns	2-8
$t_{PZH}$ $t_{PZL}$	Output Enable Time	4.0	1.5	6.2			ns	2-10
$t_{PHZ}$ $t_{PLZ}$	Output Disable Time	3.0	1.5	5.6			ns	2-10

Note 1: Minimum limits are guaranteed but not tested on propagation delays.

**Capacitance** ( $T_A = +25^\circ\text{C}$ ,  $f = 1.0\text{ MHz}$ )

Symbol	Parameter (Note)	Typ	Max	Units	Conditions
$C_{IN}$	Input Capacitance	6	10	pF	$V_{IN} = 0\text{V}$
$C_{OUT}$	Output Capacitance	8	12	pF	$V_{OUT} = 0\text{V}$

Note: This parameter is measured at characterization but not tested.